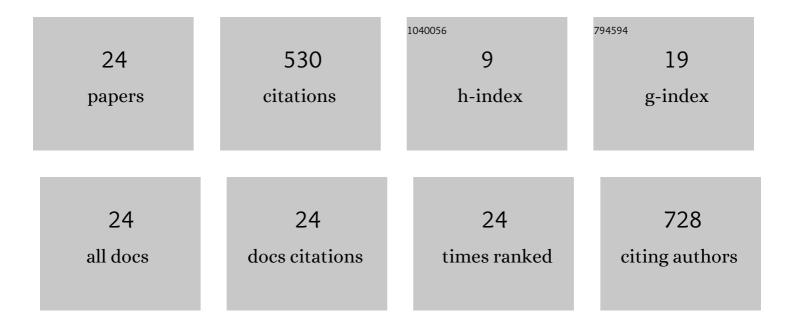
Haider Ali

List of Publications by Year in descending order

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Ηλίδερ Δι

 Phosphorus-doped polysilicon passivating contacts deposited by atmospheric pressure che deposition. Journal Physics D: Applied Physics, 2021, 54, 384003. A Combined Mechanochemical and Calcination Route to Mixed Cobalt Oxides for the Selec Catalytic Reduction of Nitrophenols. Molecules, 2020, 25, 89. Spatial Atomic Layer Deposition of Molybdenum Oxide for Industrial Solar Cells. Advanced I Interfaces, 2020, 7, 2000895. Transmission Electron Microscopy and Electron Energy-Loss Spectroscopy Studies of Hole-S Molybdenum Oxide Contacts in Silicon Solar Cells. ACS Applied Materials & amp; Interfaces, 43075-43080. Nondestructive Contact Resistivity Measurements on Solar Cells Using the Circular Transm Method. IEEE Journal of Photovoltaics, 2019, 9, 1800-1805. 	IF	CITATIONS
 ² Catalytic Reduction of Nitrophenols. Molecules, 2020, 25, 89. ³ Spatial Atomic Layer Deposition of Molybdenum Oxide for Industrial Solar Cells. Advanced I Interfaces, 2020, 7, 2000895. ⁴ Transmission Electron Microscopy and Electron Energy-Loss Spectroscopy Studies of Hole-S Molybdenum Oxide Contacts in Silicon Solar Cells. ACS Applied Materials & amp; Interfaces, 43075-43080. ⁵ Nondestructive Contact Resistivity Measurements on Solar Cells Using the Circular Transm Method. IEEE Journal of Photovoltaics, 2019, 9, 1800-1805. 	mical vapor 2.8	6
 Interfaces, 2020, 7, 2000895. Transmission Electron Microscopy and Electron Energy-Loss Spectroscopy Studies of Hole-S Molybdenum Oxide Contacts in Silicon Solar Cells. ACS Applied Materials & amp; Interfaces, 43075-43080. Nondestructive Contact Resistivity Measurements on Solar Cells Using the Circular Transm Method. IEEE Journal of Photovoltaics, 2019, 9, 1800-1805. 	tive 3.8	12
 Molybdenum Oxide Contacts in Silicon Solar Cells. ACS Applied Materials & amp; Interfaces, 43075-43080. Nondestructive Contact Resistivity Measurements on Solar Cells Using the Circular Transm Method. IEEE Journal of Photovoltaics, 2019, 9, 1800-1805. 	Materials 3.7	18
⁵ Method. IEEE Journal of Photovoltaics, 2019, 9, 1800-1805.	Selective , 2019, 11, 8.0	11
	ission Line 2.5	9
6 TEM Study of MoOx/Ni and MoOx/Al Contacts for Silicon Solar Cells. Microscopy and Micro 2019, 25, 2116-2117.	panalysis, 0.4	0
7 In Situ Transmission Electron Microscopy Study of Molybdenum Oxide Contacts for Silicon Cells. Physica Status Solidi (A) Applications and Materials Science, 2019, 216, 1800998.	Solar 1.8	6
8 Transmission Electron Microscopy Study of UV-ozone Cleaned Silicon Surfaces for Applicat High Efficiency Photovoltaics. , 2019, , .	ion in	0
9 In Situ Transmission Electron Microscopy: A Powerful Tool for the Characterization of Carrier-Selective Contacts. , 2019, , .		0
10 Effective Use of UVâ€Ozone Oxide in Silicon Solar Cell Applications. Physica Status Solidi - Research Letters, 2019, 13, 1800488.	Rapid 2.4	8
Automated detection of rear contact voids in perc cells with photoluminescence imaging. S Energy Materials and Solar Cells, 2018, 179, 31-35.	Golar 6.2	3
12 Thermally Stable Molybdenum Oxide Hole-Selective Contacts Deposited using Spatial Atom Deposition. , 2018, , .	iic Layer	5
Transmission Electron Microscopy Studies of Transition Metal Oxides Employed as Carrier S Contacts in Silicon Solar Cells. , 2018, , .	Selective	0
Simple and versatile UV-ozone oxide for silicon solar cell applications. Solar Energy Material Solar Cells, 2018, 185, 505-510.	ls and 6.2	21
¹⁵ Thermal Stability of Hole-Selective Tungsten Oxide: In Situ Transmission Electron Microscop Scientific Reports, 2018, 8, 12651.	by Study. 3.3	16
16 TEM studies of hole-selective molybdenum oxide contacts in silicon heterojunction solar ce Microscopy and Microanalysis, 2018, 24, 1508-1509.	lls. 0.4	3
Solar blind photodetector based on epitaxial zinc doped Ga ₂ O ₃ 1Physica Status Solidi (A) Applications and Materials Science, 2017, 214, 1600688.	thin film. 1.8	61
MgZnO grown by molecular beam epitaxy on N-Type Î ² -Ga ₂ O ₃ for barrier solar-blind photodetectors. Proceedings of SPIE, 2017, , .	or UV Schottky 0.8	5

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#	Article	IF	CITATIONS
19	Solar blind photodetector based on epitaxial zinc doped Ga ₂ O ₃ thin film (Phys. Status Solidi A 5â^•2017). Physica Status Solidi (A) Applications and Materials Science, 2017, 214, 1770127.	1.8	5
20	Transmission Electron Microscopy Studies of Electron-Selective Titanium Oxide Contacts in Silicon Solar Cells. Microscopy and Microanalysis, 2017, 23, 900-904.	0.4	19
21	Influence of surface preparation and cleaning on the passivation of boron diffused silicon surfaces for high efficiency photovoltaics. Thin Solid Films, 2017, 636, 412-418.	1.8	9
22	Transmission electron microscopy based interface analysis of the origin of the variation in surface recombination of silicon for different surface preparation methods and passivation materials. Physica Status Solidi (A) Applications and Materials Science, 2017, 214, 1700286.	1.8	11
23	Highâ€Performance TiO ₂ â€Based Electronâ€Selective Contacts for Crystalline Silicon Solar Cells. Advanced Materials, 2016, 28, 5891-5897.	21.0	300
24	TEM studies of TiO 2 -based passivated contacts in c-Si solar cells. Microscopy and Microanalysis, 2016, 22, 1600-1601.	0.4	2